NSN 5962-01-156-1427

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View Online at https://aerobasegroup.com/nsn/5962-01-156-1427 **Body Length:** 0.960 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Maximum Power Dissipation Rating:** 1.2 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and w/enable **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 12 input **Case Outline Source And Designator:** D-6 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Time Rating Per Chacteristic:** 70.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Ram **Memory Capacity:** Unknown **Test Data Document:** 81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:**

Shelf Life:

18 printed circuit

Specification Data:

81349-mil-m-38510/238 government specification

N/a

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Demilitarization:

Yes - demil/mli

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